

## 2SA1415/2SC3645

# High-Voltage Switching, **Predriver Applications**

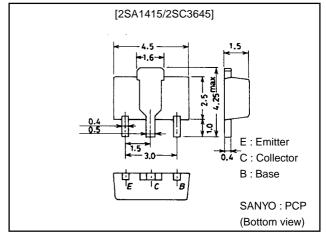
### **Features**

- · Adoption of FBET process.
- $\cdot$  High breakdown voltage (V<sub>CEO</sub>=160V).
- · Excellent linearity of hFE and small Cob.
- · Fast switching speed.
- · Very small size marking it easy to provide highdensity, small-sized hybrid ICs.

### **Package Dimensions**

unit:mm

2038



(): 2SA1415

### **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)180	V
Collector-to-Emitter Voltage	VCEO		(–)160	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)5	V
Collector Current	lс		(-)140	mA
Collector Current (Pulse)	I <sub>CP</sub>		(–)200	mA
Collector Dissipation	P <sub>C</sub> 1		500	mW
	P <sub>C</sub> 2	Moutned on ceramic board (250mm²×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)80V, I <sub>E</sub> =0			(-)100	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(–)100	nA
DC Current Gain	hFE	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)10mA	100*		400*	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)10mA		150		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(4.0)		pF
				3.0		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)50mA, I <sub>B</sub> =(-)5mA		(-0.14)	(-0.4)	V
				0.07	0.3	V
Turn-ON Time	ton	See sepcified Test Circuit.		0.1		μs
Storage Time	t <sub>stg</sub>	See sepcified Test Circuit.		1.5		μs
Fall Time	t <sub>f</sub>	See sepcified Test Circuit.		0.1		μs

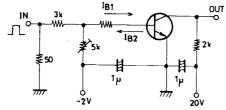
<sup>\* :</sup> The 2SA1415/2SC3645 are classified by 10mA  $h_{\mbox{\scriptsize FE}}$  as follows :

100 R 200 140 S 280 200 T h<sub>FE</sub> rank: R, S, T

Marking 2SA1415: AA

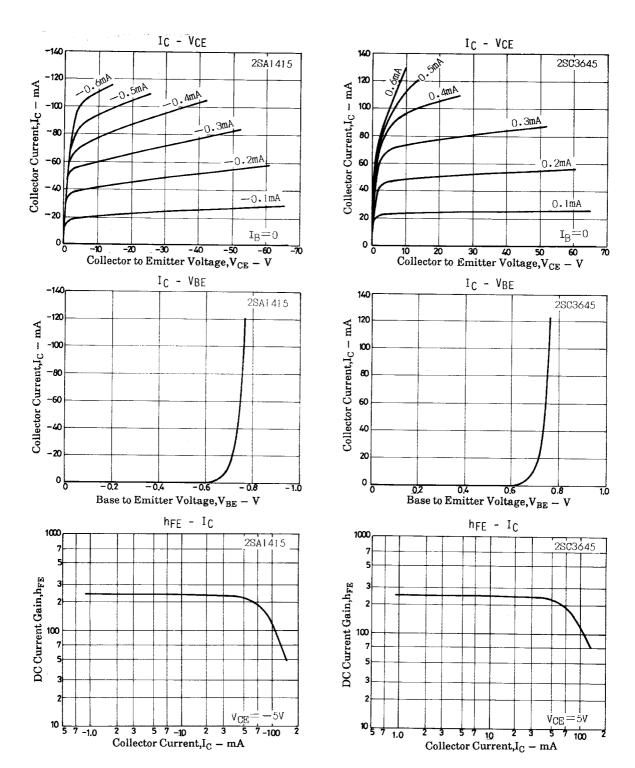
2SC3645 : CA

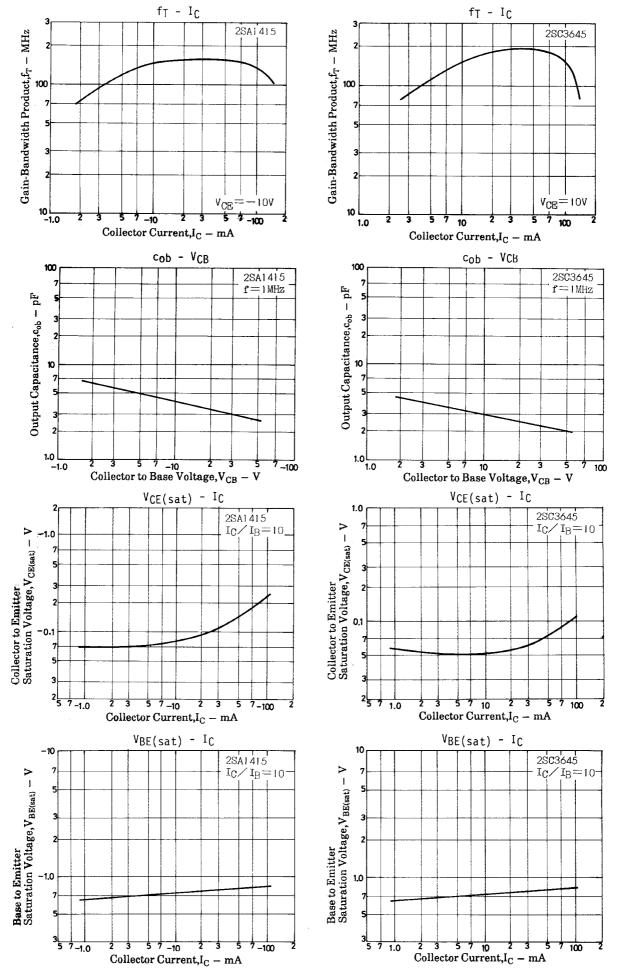
### **Switching Time Test Circuit**



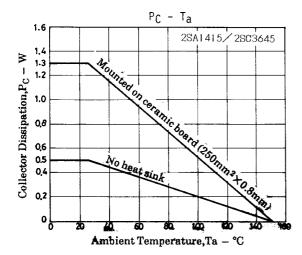
 $I_C = 10I_{B1} = 10I_{B2} = 10mA$ 

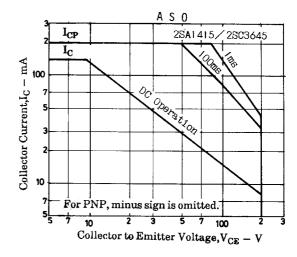
(For PNP, the polarity is reversed) Unit (resistance :  $\Omega$ , capacitance : F)





### 2SA1415/2SC3645





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